

Dual D-Type Flip-Flop with Preset and Clear 74VHC74

General Description

The VHC74 is an advanced high speed CMOS Dual D–Type Flip–Flop fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The signal level applied to the D input is transferred to the Q output during the positive going transition of the CK pulse. $\overline{\text{CLR}}$ and $\overline{\text{PR}}$ are independent of the CK and are accomplished by setting the appropriate input LOW.

An input protection circuit ensures that $0\ V$ to $5.5\ V$ can be applied to the input pins without regard to the supply voltage. This device can be used to interface $5\ V$ to $3\ V$ systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed: $f_{MAX} = 170 \text{ MHz}$ (Typ.) at $T_A = 25^{\circ}\text{C}$
- High Noise Immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Power Down Protection is Provided on All Inputs
- Low Power Dissipation: $I_{CC} = 2 \mu A$ (Max.) at $T_A = 25^{\circ}C$
- Pin and Function Compatible with 74HC74
- Pb-Free, Halogen Free/BFR Free and RoHS Compliant

Logic Symbol

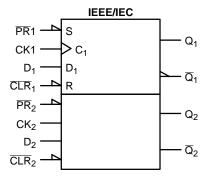


Figure 1. Logic Symbol

TRUTH TABLE

	Inp	uts		Out		
CLR	PR	D	CK	Q	Q	Function
L	Н	Х	Х	L	Н	Clear
Н	L	Х	Х	Н	L	Preset
L	L	Х	Х	H (Note 1)	H (Note 1)	
Н	Н	L	~	L	Н	
Н	Н	Н	<i></i>	Н	L	
Н	Н	Х	~	Q _n	\overline{Q}_n	No Change

This configuration is nonstable; that is, it will not persist when preset and clear inputs return to their inactive (HIGH) state.



MARKING DIAGRAM

CASE 948G

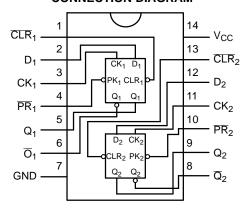


XXXXX = Specific Device Code A = Assembly Location

L = Wafer Lot
Y = Year
W = Work Week
• Pb-Free Package

(Note: Microdot may be in either location)

CONNECTION DIAGRAM



PIN DESCRIPTION

Pin Names	Description
D ₁ , D ₂	Data Inputs
CK ₁ , CK ₂	Clock Pulse Inputs
CLR ₁ , CLR ₂	Direct Clear Inputs
PR ₁ , PR ₂	Direct Preset Inputs
$Q_1, \overline{Q}_1, Q_2, \overline{Q}_2$	Output

ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

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MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to +6.5	V
V _{IN}	DC Input Voltage	-0.5 to +6.5	V
V _{OUT}	DC Output Voltage	-0.5 to V _{CC} + 0.5	V
I _{IN}	DC Input Current, Per Pin	±20	mA
I _{OUT}	DC Output Current, Per Pin	±25	mA
Icc	DC Supply Current, V _{CC} and GND Pins	±50	mA
I _{IK}	Input Clamp Current	-20	mA
lok	Output Clamp Current	±20	mA
T _{STG}	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 s	260	°C
TJ	Junction Temperature Under Bias	+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2)	150	°C/W
P_{D}	Power Dissipation in Still Air at 25°C	833	mW
V _{ESD}	ESD Withstand Voltage (Note 3) Human Body Model Charged Device Model	>2000 N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage	4.5	5.5	V
V _{IN}	DC Input Voltage (Note 4)	0	5.5	V
V _{OUT}	DC Output Voltage (Note 4)	0	V_{CC}	V
T _A	Operating Temperature	-40	+85	°C
t _r , t _f	Input Rise or Fall Rate V _{CC} = 3.0 V to 3.6 V V _{CC} = 4.5 V to 5.5 V	0	100 20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must be held HIGH or LOW. They may not float.

Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
 HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

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DC ELECTRICAL CHARACTERISTICS

						T _A = 25°C		$T_A = -40^{\circ}$	C to +85°C	
Symbol	Parameter	V _{CC} (V)	Con	ditions	Min	Тур	Max	Min	Max	Unit
V_{IH}	HIGH Level Input	2.0			1.50	-	_	1.50	_	V
	Voltage	3.0-5.5	1		0.7 x V _{CC}	-	-	0.7 x V _{CC}	_	
V _{IL}	LOW Level Input	2.0			-	-	0.50	-	0.50	V
	Voltage	3.0-5.5]		-	-	0.3 x V _{CC}	-	0.3 x V _{CC}	
V _{OH}	HIGH Level Output	2.0	$V_{IN} = V_{IH}$	I _{OH} = -50 μA	1.9	2.0	_	1.9	_	V
	Voltage	3.0	or V _{IL}		2.9	3.0	_	2.9	_	
		4.5			4.4	4.5	-	4.4	_	
		3.0	1	I _{OH} = -4 mA	2.58	-	-	2.48	_	
		4.5	1	I _{OH} = -8 mA	3.94	-	-	3.80	_	
V _{OL}	LOW Level Output	2.0	$V_{IN} = V_{IH}$	I _{OL} = 50 μA	-	0.0	0.1	-	0.1	V
	Voltage	3.0	or V _{IL}		-	0.0	0.1	-	0.1	
		4.5	1		-	0.0	0.1	-	0.1	
		3.0	1	I _{OL} = 4 mA	-	-	0.36	-	0.44	
		4.5	1	I _{OL} = 8 mA	-	-	0.36	-	0.44	
I _{IN}	Input Leakage Current	0–5.5	V _{IN} = 5.5 V	or GND	_	-	±0.1	-	±1.0	μΑ
I _{CC}	Quiescent Supply Current	5.5	$V_{IN} = V_{CC}$	or GND	-	-	2.0	-	20.0	μΑ

AC ELECTRICAL CHARACTERISTICS

					T _A = 25°C		$T_A = -40^{\circ}$	C to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
f_{MAX}	Maximum Clock	3.3 ±0.3	C _L = 15 pF	80	125	-	70	_	MHz
	Frequency		C _L = 50 pF	50	75	-	45	_	
		5.0 ±0.5	C _L = 15 pF	130	170	-	110	-	
			C _L = 50 pF	90	115	-	75	_	
t _{PLH} ,	$ \begin{array}{c} t_{PLH}, \\ t_{PHL} \end{array} \begin{array}{c} \text{Propagation Delay} \\ \text{Time (CK-Q, \overline{Q})} \end{array} $	3.3 ±0.3	C _L = 15 pF	-	6.7	11.9	1.0	14.0	ns
t _{PHL}		HL Time (CK-Q, Q)		C _L = 50 pF	-	9.2	15.4	1.0	17.5
		5.0 ±0.5	C _L = 15 pF	-	4.6	7.3	1.0	8.5	
			C _L = 50 pF	-	6.1	9.3	1.0	10.5	
t _{PLH} ,	t _{PLH} , Propagation Delay	3.3 ±0.3	C _L = 15 pF	-	7.6	12.3	1.0	14.5	ns
t _{PHL}	Time (\overline{CLR} , \overline{PR} –Q, \overline{Q})		C _L = 50 pF	-	10.1	15.8	1.0	18.0	
		5.0 ±0.5	C _L = 15 pF	-	4.8	7.7	1.0	9.0	
			C _L = 50 pF	-	6.3	9.7	1.0	11.0	
C _{IN}	Input Capacitance		V _{CC} = Open	-	4	10	-	10	pF
C _{PD}	Power Dissipation Capacitance		(Note 5)	-	25	-	-	-	pF

C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} × V_{CC} × f_{IN} + I_{CC} / 2 (per F/F)

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AC OPERATING REQUIREMENTS

		V _{CC} (V)	T _A =	25°C	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	
Symbol	Parameter	(Note 6)	Тур	Guara	anteed Minimum	Unit
t _W (L),	Minimum Pulse Width (CK)	3.3	-	6.0	7.0	ns
t _W (H)		5.0	-	5.0	5.0	
$t_W(L)$	Minimum Pulse Width (CLR, PR)	3.3	-	6.0	7.0	ns
		5.0	-	5.0	5.0	ns
t _S	Minimum Setup Time	3.3	-	6.0	7.0	ns
		5.0	-	5.0	5.0	
t _H	Minimum Hold Time	3.3	-	0.5	0.5	ns
		5.0	-	0.5	0.5	
t _{REC}	Minimum Recovery Time (CLR, PR)	3.3	-	5.0	5.0	ns
		5.0	-	3.0	3.0	ns

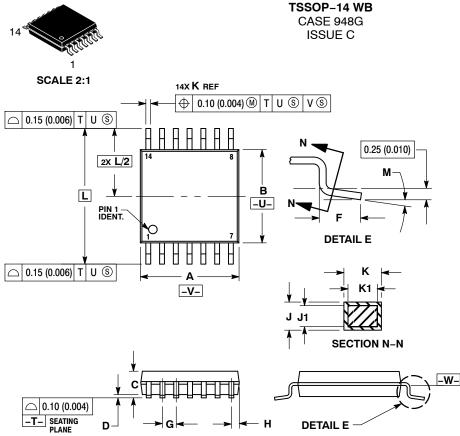
^{6.} V_{CC} is 3.3 ±0.3 V or 5.0 ±0.5 V

ORDERING INFORMATION

Device Order Number	Top Marking	Package Type	Shipping [†]
74VHC74MTCX	VHC 74	TSSOP-14 WB (Pb-Free, Halide Free)	2,500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





DATE 17 FEB 2016

- NOTES.

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

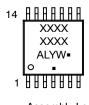
 3. DIMENSION A DOES NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE
- INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL
- INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

 6. TERMINAL NUMBERS ARE SHOWN FOR DECEDEDIC ONLY
- REFERENCE ONLY.
 DIMENSION A AND B ARE TO BE
 DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026	BSC
Н	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40		0.252	BSC
М	0 °	8 °	0 °	8 °

GENERIC MARKING DIAGRAM*



= Assembly Location

= Wafer Lot V = Year

W = Work Week

= Pb-Free Package (Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

SOLDERI	NG FOOTPRINT
<	7.06
1	
	0.65 PITCH
14X 0.36	
1.20	DIMENSIONS: MILLIMETERS

DOCUMENT NUMBER:	98ASH70246A	Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	TSSOP-14 WB		PAGE 1 OF 1		

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